

L Number	Hits	Search Text	DB	Time stamp
-	2248	((438/199) or (438/135) or (438/153) or (438/154) or (438/201) or (438/627) or (257/204)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 17:04
-	560	((438/199) or (438/135) or (438/153) or (438/154) or (438/201) or (438/627) or (257/204)).CCLS.) and (BPSG or PSG or glass)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/12 10:48
-	2820	gate and (oxide same barrier) and (BPSG or PSG or glass)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 14:19
-	5227	(CMOS) and (oxide same (furnace or photoexcitation or (photo near excitation) or microwave or ozone or steam or plasma))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 13:12
-	4348	(CMOS) and (oxide same (furnace and photoexcitation or (photo near excitation) and microwave and ozone and steam or plasma))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 13:13
-	4348	(CMOS) and (oxide same (furnace and photoexcitation and microwave and ozone and steam or plasma))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 13:20
-	0	(CMOS) and (oxide same (furnace and photoexcitation and microwave and ozone and steam and plasma))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 13:20
-	1	(CMOS) and (oxide same (photoexcitation))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 13:47
-	0	(oxygen near source) same (photoexcitation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 13:49
-	102	oxide same photoexcitation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 13:50
-	17	((silicon near oxide) same photoexcitation) or (silicon same oxide same photoexcitation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 14:18
-	2893	((silicon near oxide) same steam) or (silicon same oxide same steam)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 13:58
-	1514	((silicon near oxide) same steam) or (silicon same oxide same steam) and CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 14:08
-	898	((silicon near oxide) same microwave) or (silicon same oxide same microwave)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 14:41

-	1738	((silicon near oxide) same ozone) or (silicon same oxide same ozone)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 14:42
-	265	((silicon near oxide) same ozone) or (silicon same oxide same ozone)) and CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 14:42
-	46	(source or drain) same (atomic near oxygen) same (oxidizing)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/23 13:03
-	28	(source or drain) same (atomic near oxygen) same (oxidizing) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/23 13:04
-	21	(source or drain) same (atomic near oxygen) same (oxidizing) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/23 13:04
-	14516	(oxid\$3 same (source and drain)) and CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 17:04
-	4037	((oxid\$3 with surface) same (source and drain)) and CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 17:05
-	211	((oxidize or oxidizing) with surface) same (source and drain)) and CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 17:06
-	102	((oxidize or oxidizing) with surface) with (source and drain)) and CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 17:07
-	26	((oxidize or oxidizing) near surface) with (source and drain)) and CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 17:20
-	1	(atomic near oxygen) and ((oxidize or oxidizing) near surface) with (source and drain)) and CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 17:21
-	12	(atomic near oxygen) same (oxidize or oxidizing)and CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/08 11:45
-	288	(steam) same (oxidize or oxidizing)and CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/08 11:45
-	118	(water near vapor) same (oxidize or oxidizing)and CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/08 11:46

-	91	(water near vapor) same (oxidize or oxidizing)and CMOS	USPAT; EPO; JPO; DERWENT; IBM TDB USPAT	2003/12/08 13:22
-	2	(("5607874") or ("6288438")).PN.	USPAT	2003/12/08 13:23